# Ultrafast Soft Recovery Diode, 150 A FRED Pt<sup>®</sup>



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**PowerTab**®

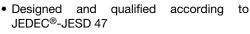
### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	150 A				
V <sub>R</sub>	400 V				
V <sub>F</sub> at I <sub>F</sub>	0.9 V				
t <sub>rr</sub> (typ.)	See recovery table				
T <sub>J</sub> max.	175 °C				
Package	PowerTab <sup>®</sup>				
Circuit configuration	Single				

### **FEATURES**

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only



 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

#### **DESCRIPTION / APPLICATIONS**

These diodes are optimized to reduce losses and EMI/RFI in power high frequency conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

### **MECHANICAL DATA**

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating Terminal: nickel plated, screwable

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V <sub>R</sub>		400	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 104 °C	150	
Single pulse forward current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	1500	A
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20 kHz	300	
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	I <sub>R</sub> = 200 μA	400	-	-		
		I <sub>F</sub> = 150 A	-	1.07	1.3	v	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 150 A, T <sub>J</sub> = 175 °C	-	0.9	1.1		
		I <sub>F</sub> = 150 A, T <sub>J</sub> = 125 °C	-	0.96	1.17		
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	-	50	μA	
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	4	mA	
Junction capacitance	CT	V <sub>R</sub> = 400 V	-	100	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 3.5 -		nH			

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## **Vishay Semiconductors**

DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A},  dI_F/dt = 200 \text{ A}$	A/μs, V <sub>R</sub> = 30 V	-	-	60	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	93	-	ns
		T <sub>J</sub> = 125 °C		-	172	-	
Peak recovery current I <sub>RRM</sub>	1	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 150 A V <sub>B</sub> = 200 V	-	11	-	А
	T <sub>J</sub> = 125 °C	v <sub>R</sub> = 200 v dI <sub>F</sub> /dt = 200 A/μs	-	20	-	~	
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	490	-	nC
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1740	-	nc

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.22	0.29	K/W
Thermal resistance, junction to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.2	-	r\/ vv
Weight			-	-	5.02	g
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style PowerTab <sup>®</sup>		150E	BU04	

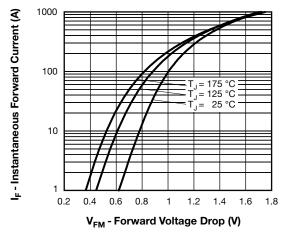


Fig. 1 - Maximum Forward Voltage Drop Characteristics

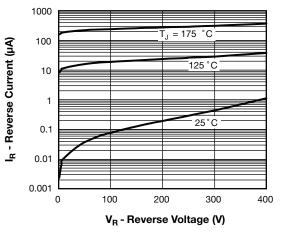
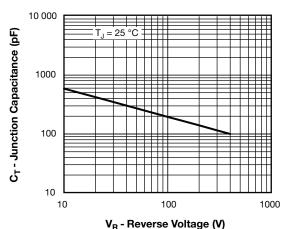


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

## VS-150EBU04-N4

### **Vishay Semiconductors**







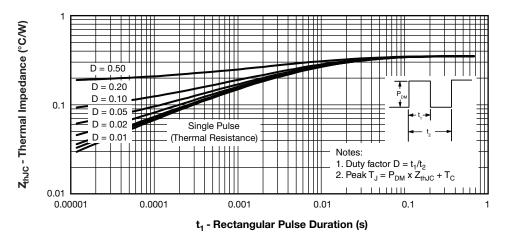
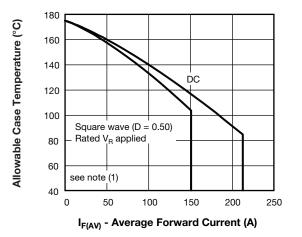
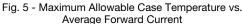


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = I_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = V_{R1} \times I_R \mbox{ (1 - D); } I_R \mbox{ at } V_{R1} = Rated \ V_R \end{array}$ 

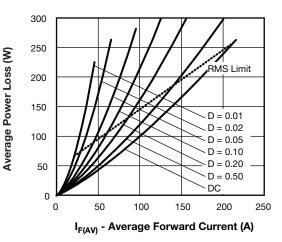


Fig. 6 - Forward Power Loss Characteristics

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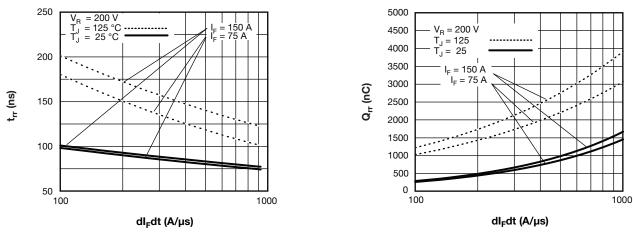


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

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Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

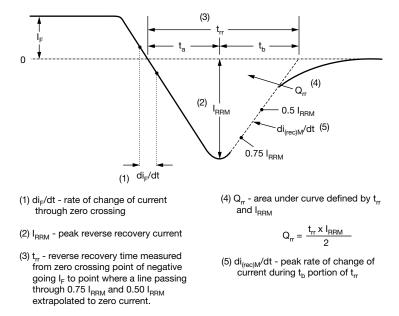


Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

Device code	VS-	150	Е	в	U	04	-N4
	1	2	3	4	5	6	7
	1 -	Visł	nay Sem	niconduc	tors pro	duct	
	2 -	Cur	rent rati	ng (150	= 150 A	.)	
	3 -	Sing	gle diode	е			
	4 -	Pow	/erTab <sup>®</sup>	(ultrafa	st / hype	erfast or	ıly)
	5 -	Ultra	afast reo	covery			
	6 -	Volt	age rati	ng (04 =	400 V)		
	7 -			ntal digit			امت م

-N4 = Halogen-free, RoHS-compliant, and totally lead(Pb)-free

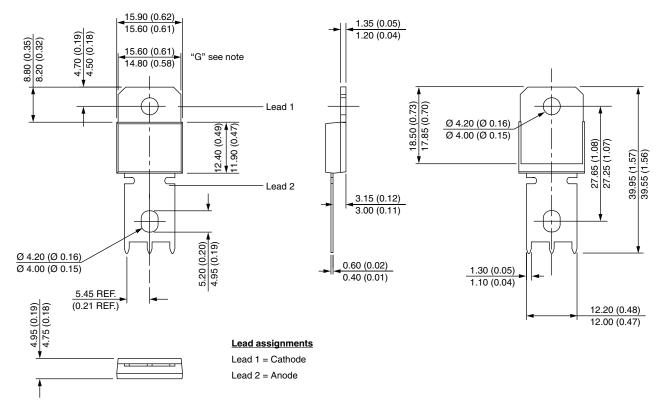
ORDERING INFORMATION		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-150EBU04-N4	25/tube	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			



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### **DIMENSIONS** in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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